

INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)			ATTY. DOCKET NO. 57810-098	SERIAL NO.		
			APPLICANT Kenya UESUGI, et al.			
			FILING DATE March 30, 2004	GROUP		
U.S. PATENT DOCUMENTS						
EXAMINER'S INITIALS	CITE NO.	Document Number Number-Kind Code(s if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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FOREIGN PATENT DOCUMENTS						
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		<u>Seigo KISHINO, "Basis of Semiconductor Device", Published by Ohmsha, Ltd., April 25, 1985</u> <u>"Sub-micron Device I", pp. 40-54, July 84, 1987</u>				
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